

## 6508A

Isolated Diode Array with HiRel MQ, MX, MV, and SP Screening Options

## DESCRIPTION

These low capacitance diode arrays are multiple, discrete, isolated junctions fabricated by a planar process and mounted in a 14-PIN ceramic DIP package for use as steering diodes protecting up to eight I/O ports from ESD, EFT, or surge by directing them to the positive side of the power supply line and to ground (see Figure 1). An external TVS diode may be added between the positive supply line and ground to prevent overvoltage on the supply rail. They may also be used in fast switching core-driver applications. This includes computers and peripheral equipment such as magnetic cores, thin-film memories, plated-wire memories, etc., as well as decoding or encoding applications. These arrays offer many advantages of integrated circuits such as highdensity packaging and improved reliability. This is a result of fewer pick and place operations, smaller footprint, smaller weight, and elimination of various discrete packages that may not be as user friendly in PC board mounting.

IMPORTANT: For the most current data, consult MICROSEMI's website: http://www.microsemi.com

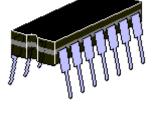
# FEATURES

- Hermetic Ceramic Package
- Isolated Diodes to Eliminate Cross-Talk Voltages
- High Breakdown Voltage  $V_{BR} > 60$  V at 10  $\mu$ A
- Low Leakage I<sub>R</sub>< 100nA at 40 V</li>
- Low Capacitance C < 8.0 pF
- Switching Speeds less than 20 ns
- Options for screening in accordance with MIL-PRF-19500/474 for JAN, JANTX, JANTXV, and JANS are available by adding MQ, MX, MV, or SP prefixes respectively to part numbers. For example, designate MX6508A for a JANTX screen.

### MAXIMUM RATINGS

- Reverse Breakdown Voltage of 60 Vdc (Note 1 & 2)
- Continuous Forward Current of 300 mA dc (Note 1 & 3)
- Peak Surge Current (tp=1/120 s) of 500 mA dc (Note 1)
- 400 mW Power Dissipation per Junction @ 25°C
- 600 mW Power Dissipation per Package @ 25°C (Note 4)
- Operating Junction Temperature range –65 to +150°C
- Storage Temperature range of –65 to +150°C
  - NOTE 1: Each Diode
  - **NOTE 2:** Pulsed:  $P_W = 100 \text{ ms max}$ ; duty cycle  $\leq 20\%$
  - **NOTE 3:** Derate at 2.4 mA/°C above +25°C
  - **NOTE 4:** Derate at 4.8 mW/°C above +25°C

# APPEARANCE



14-PIN Ceramic DIP

## **APPLICATIONS / BENEFITS**

- High Frequency Data Lines
- RS-232 & RS-422 Interface Networks
- Ethernet: 10 Base T
- Computer I/O Ports
- LAN
- Switching Core Drivers
- IEC 61000-4 Compatible (see circuit in figure 1) 61000-4-2 ESD: Air 15 kV, contact 8 kW 61000-4-4 (EFT): 40 A – 5/50 ns 61000-4-5 (surge): 12 A 8/20 μs

### MECHANICAL AND PACKAGING

- 14-PIN Ceramic DIP
- Weight 2.05 grams (approximate)
- Marking: Logo, part number, date code
- Pin #1 to the left of the indent on top of package
- Carrier Tubes; 25 pcs (standard)

PART	MAXIMUM FORWARD VOLTAGE V <sub>F1</sub> I <sub>F</sub> = 100 mA (Note 1)	MAXIMUM REVERSE CURRENT I <sub>R1</sub> V <sub>R</sub> = 40 V	$\begin{tabular}{lllllllllllllllllllllllllllllllllll$	MAXIMUM FORWARD RECOVERY TIME t <sub>fr</sub> I <sub>F</sub> = 500 mA	$\begin{array}{c} \text{MAXIMUM} \\ \text{REVERSE} \\ \text{RECOVERY TIME} \\ \text{trr} \\ \text{I}_{\text{F}} = \text{I}_{\text{R}} = 200 \text{ mA} \\ \text{i}_{\text{rr}} = 20 \text{ mA} \\ \text{R}_{\text{L}} = 100 \text{ ohms} \end{array}$
NUMBER	V	μA	pF	ns	ns
6508A	1	0.1	8.0	40	20

**NOTE 1:** Pulsed:  $P_W$  = 300 us +/- 50 µs, duty cycle <2%, 90 µs after leading edge.



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Symbol	DEFINITION				
$V_{BR}$	Minimum Breakdown Voltage: The minimum voltage the device will exhibit at a specified current.				
V <sub>F</sub>	Maximum Forward Voltage: The maximum forward voltage the device will exhibit at a specified current.				
I <sub>R</sub>	Maximum Leakage Current: The maximum leakage current that will flow at the specified voltage and				
יא	temperature.				
Ct	picofarads.	ance of the TVS as defined @ 0 volts at a frequency of 1 MHz and stated in			
	picolalaus.				
<b>C</b>					
2	CHEMATIC	PACKAGE DIMENSIONS			
12	20 🔁 📔	.290			
1		200 MAX			
	ъ 🖣	1200 MAX			
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$\begin{array}{c} \circ \circ \circ \\ \bullet & \bullet \end{array}$	O 13 Not Connected				
4 0 10	13 Not Connected				
		.015			
	CIRCUIT				
Supply	$v \text{ rail } (+V_{\text{CC}})$	0015			
	1	800.			
O Port —					
	$\pm$				
	<b>—</b>				
GNI	$O(\text{or} - V_{CC})$				
UNL					
<u>Steering</u> D	iode Application				
-	URE 1				

**SYMBOLS & DEFINITIONS** 

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